

# MUR1610CTG, MUR1615CTG, MUR1620CTG, MUR1640CTG, MUR1660CTG

## Switch Mode Power Rectifiers

These state-of-the-art devices are a series designed for use in switching power supplies, inverters and as free wheeling diodes.

### Features

- Ultrafast 35 and 60 Nanosecond Recovery Times
- 175°C Operating Junction Temperature
- Popular TO-220 Package
- Epoxy Meets UL 94 V-0 @ 0.125 in
- High Temperature Glass Passivated Junction
- High Voltage Capability to 600 V
- Low Leakage Specified @ 150°C Case Temperature
- Current Derating @ Both Case and Ambient Temperatures
- These are Pb-Free Devices\*

### Mechanical Characteristics:

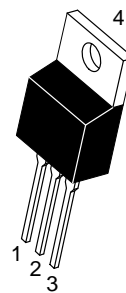
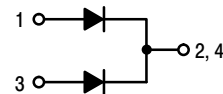
- Case: Epoxy, Molded
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes:  
260°C Max. for 10 Seconds



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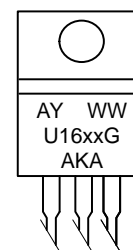
[www.onsemi.com](http://www.onsemi.com)

## ULTRAFAST RECTIFIERS 16 AMPERES, 100-600 VOLTS



TO-220AB  
CASE 221A-09

### MARKING DIAGRAM



- A = Assembly Location
- Y = Year
- WW = Work Week
- U16xx = Device Code  
xx = 10, 15, 20, 40 or 60
- G = Pb-Free Package
- KA = Diode Polarity

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

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## MAXIMUM RATINGS

Rating	Symbol	MUR16					Unit
		10CT	15CT	20CT	40CT	60CT	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$V_{RRM}$ $V_{RWM}$ $V_R$	100	150	200	400	600	V
Average Rectified Forward Current Total Device, (Rated $V_R$ ), $T_C = 150^\circ\text{C}$	$I_{F(AV)}$ Per Leg Total Device	8.0 16					A
Peak Rectified Forward Current (Rated $V_R$ , Square Wave, 20 kHz), $T_C = 150^\circ\text{C}$	$I_{FM}$ Per Diode Leg	16					A
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	$I_{FSM}$	100					A
Operating Junction Temperature and Storage Temperature	$T_J, T_{stg}$	-65 to +175					$^\circ\text{C}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

## THERMAL CHARACTERISTICS (Per Diode Leg)

Parameter	Symbol	Value		Unit
Maximum Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	3.0	2.0	$^\circ\text{C/W}$

## ELECTRICAL CHARACTERISTICS (Per Diode Leg)

Characteristic	Symbol	1620	1640	1660	Unit
Maximum Instantaneous Forward Voltage (Note 1) ( $I_F = 8.0\text{ A}$ , $T_C = 150^\circ\text{C}$ ) ( $I_F = 8.0\text{ A}$ , $T_C = 25^\circ\text{C}$ )	$V_F$	0.895 0.975	1.00 1.30	1.20 1.50	V
Maximum Instantaneous Reverse Current (Note 1) (Rated DC Voltage, $T_C = 150^\circ\text{C}$ ) (Rated DC Voltage, $T_C = 25^\circ\text{C}$ )	$i_R$	250 5.0	500 10		$\mu\text{A}$
Maximum Reverse Recovery Time ( $I_F = 1.0\text{ A}$ , $di/dt = 50\text{ A}/\mu\text{s}$ ) ( $I_F = 0.5\text{ A}$ , $I_R = 1.0\text{ A}$ , $I_{REC} = 0.25\text{ A}$ )	$t_{rr}$	35 25	60 50		ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse Test: Pulse Width = 300  $\mu\text{s}$ , Duty Cycle  $\leq 2.0\%$

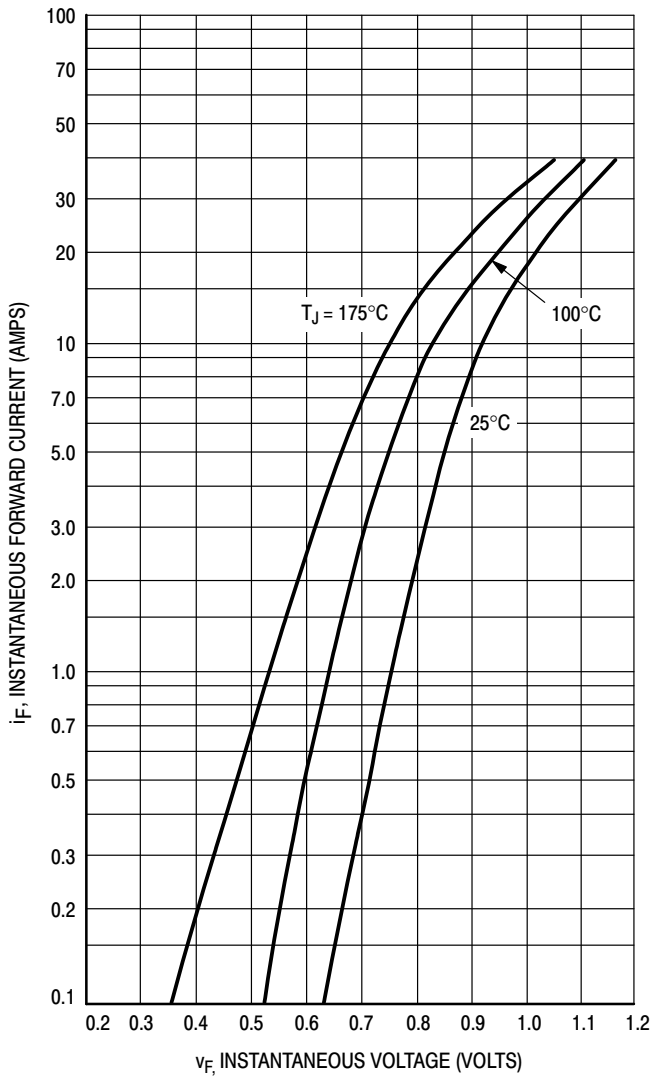


Figure 1. Typical Forward Voltage, Per Leg

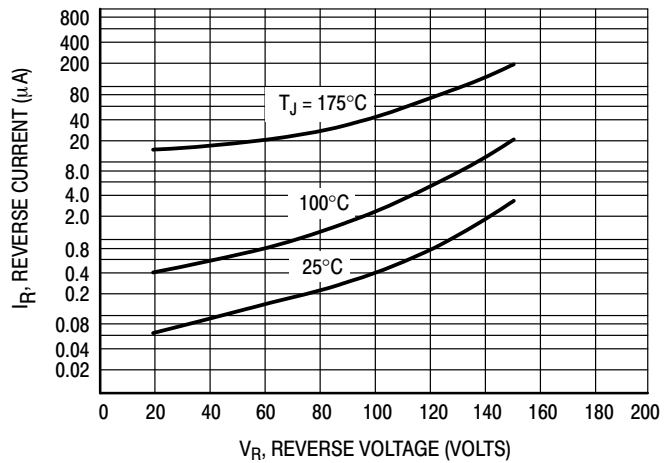


Figure 2. Typical Reverse Current, Per Leg\*

\* The curves shown are typical for the highest voltage device in the voltage grouping. Typical reverse current for lower voltage selections can be estimated from these same curves if  $V_R$  is sufficiently below rated  $V_R$ .

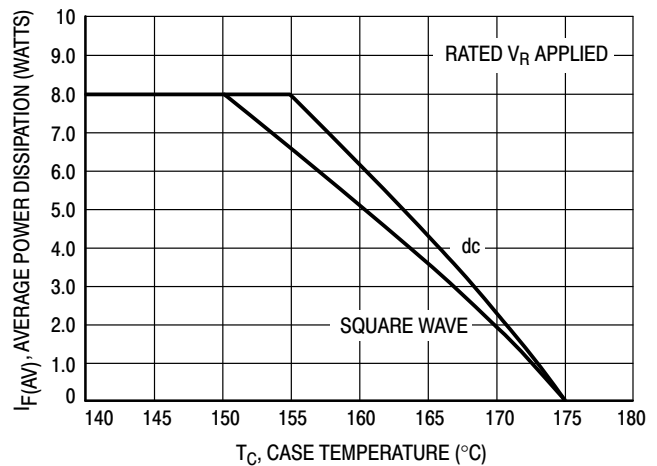


Figure 3. Current Derating, Case, Per Leg

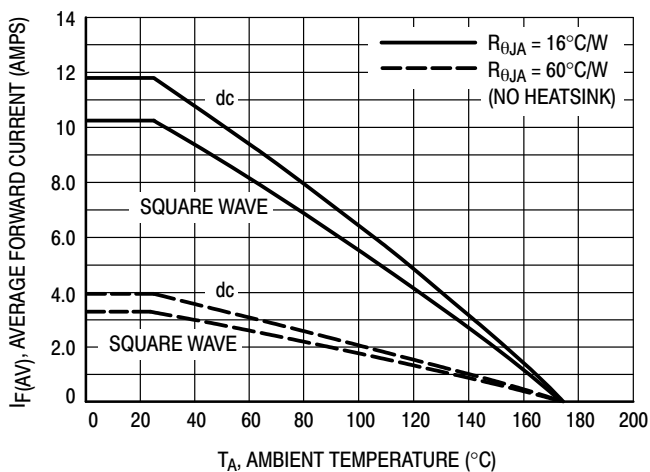


Figure 4. Current Derating, Ambient, Per Leg

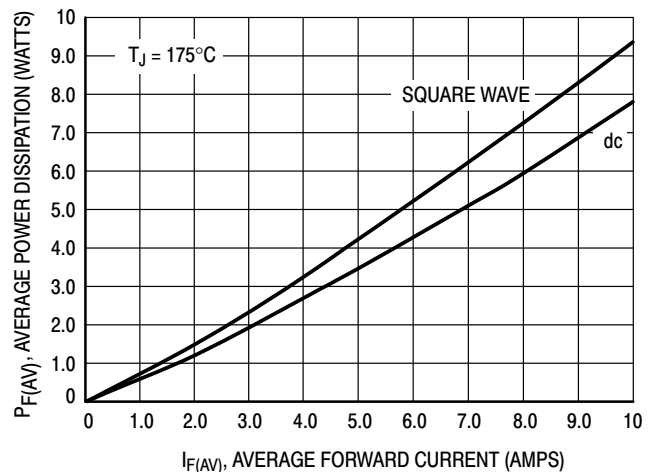


Figure 5. Power Dissipation, Per Leg

MUR1640CT

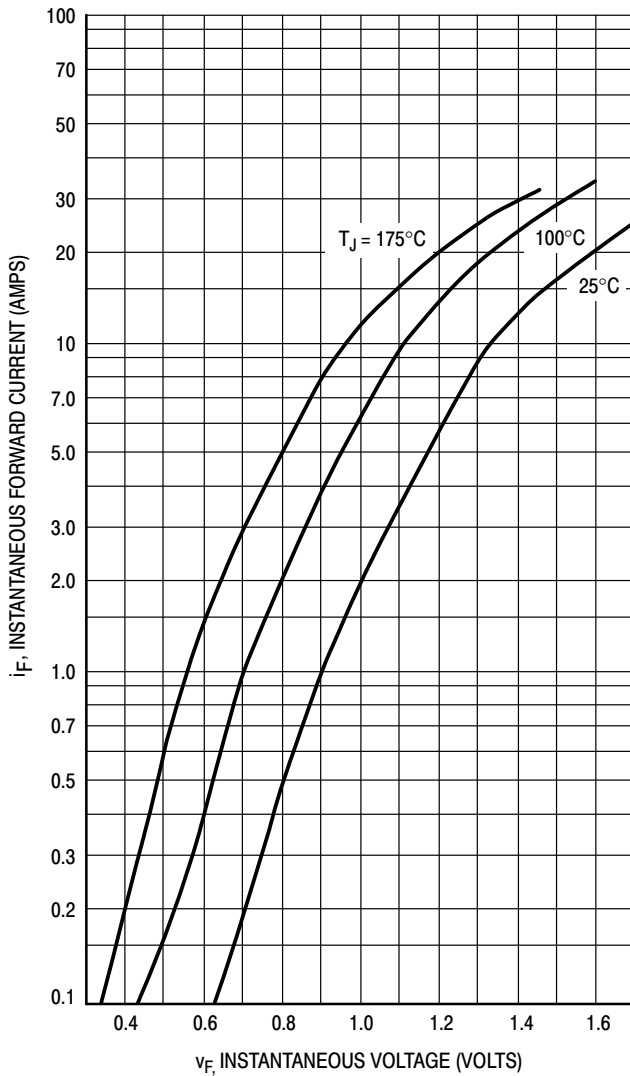


Figure 6. Typical Forward Voltage, Per Leg

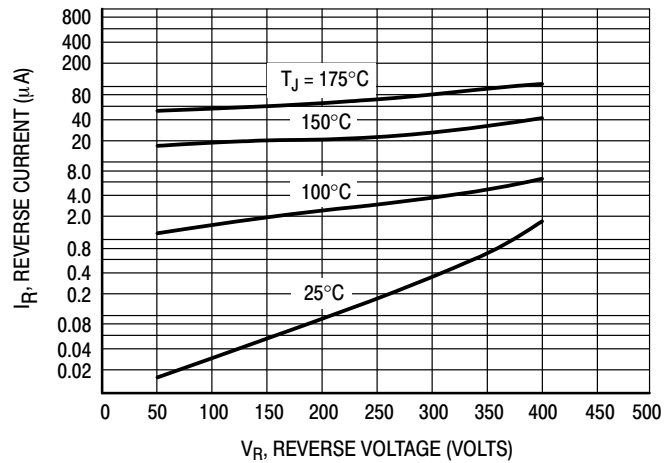


Figure 7. Typical Reverse Current, Per Leg\*

\* The curves shown are typical for the highest voltage device in the voltage grouping. Typical reverse current for lower voltage selections can be estimated from these curves if  $V_R$  is sufficiently below rated  $V_R$ .

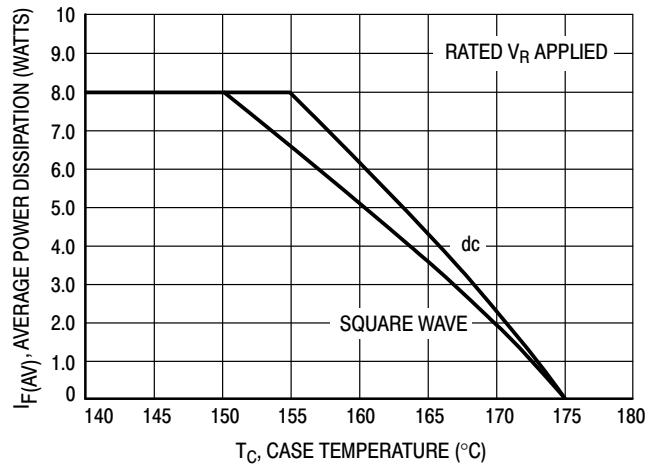


Figure 8. Current Derating, Case, Per Leg

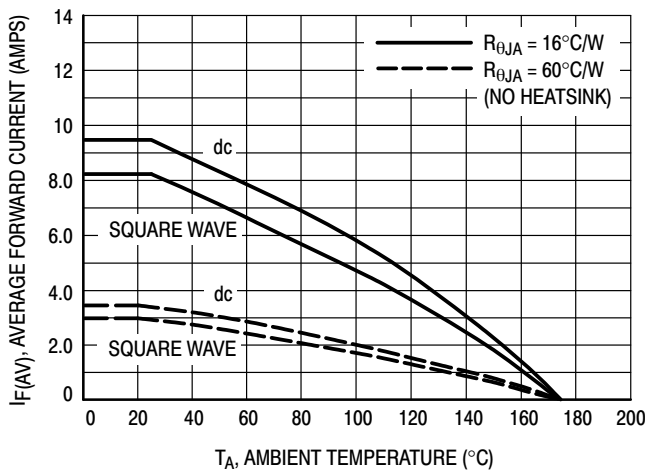


Figure 9. Current Derating, Ambient, Per Leg

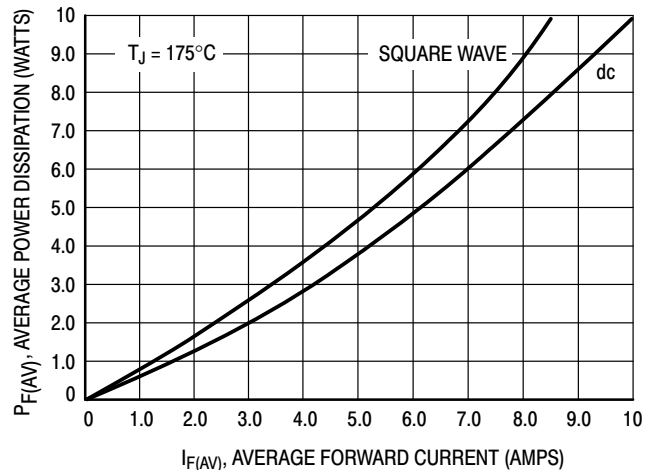


Figure 10. Power Dissipation, Per Leg

MUR1660CT

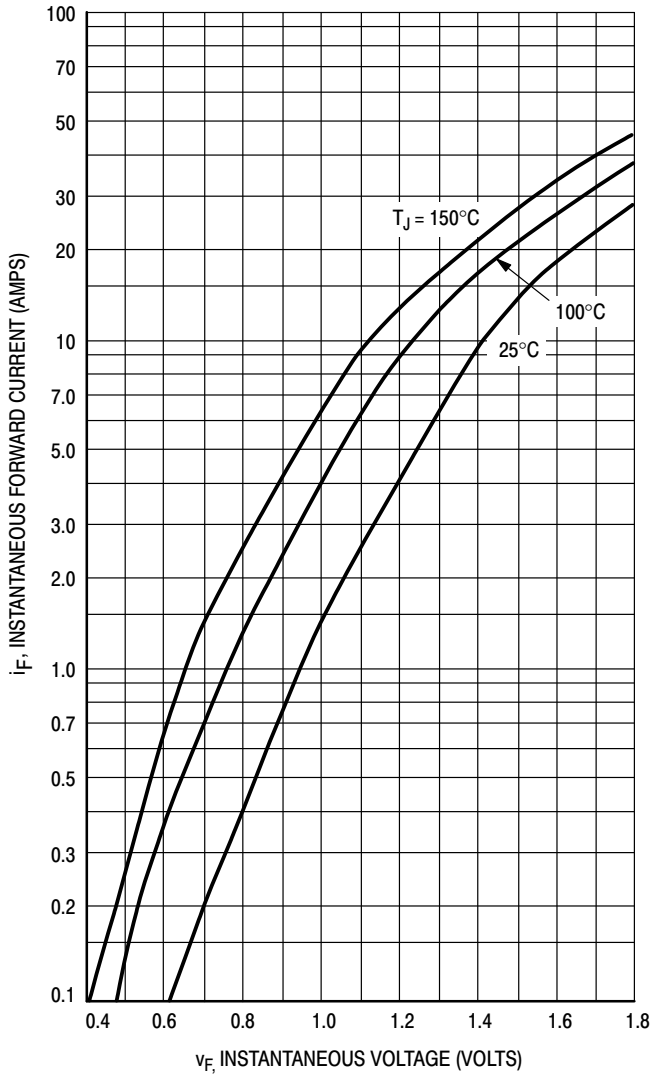


Figure 11. Typical Forward Voltage, Per Leg

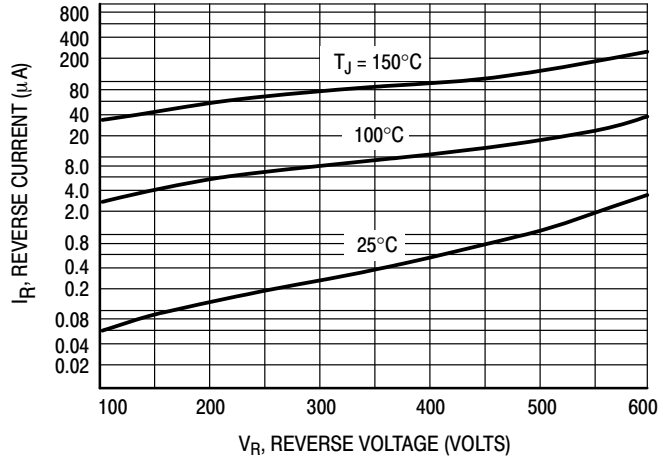


Figure 12. Typical Reverse Current, Per Leg\*

\* The curves shown are typical for the highest voltage device in the voltage grouping. Typical reverse current for lower voltage selections can be estimated from these same curves if  $V_R$  is sufficiently below rated  $V_R$ .

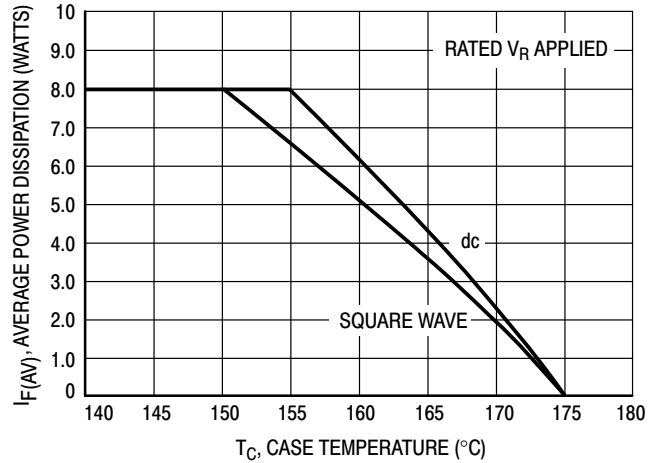


Figure 13. Current Derating, Case, Per Leg

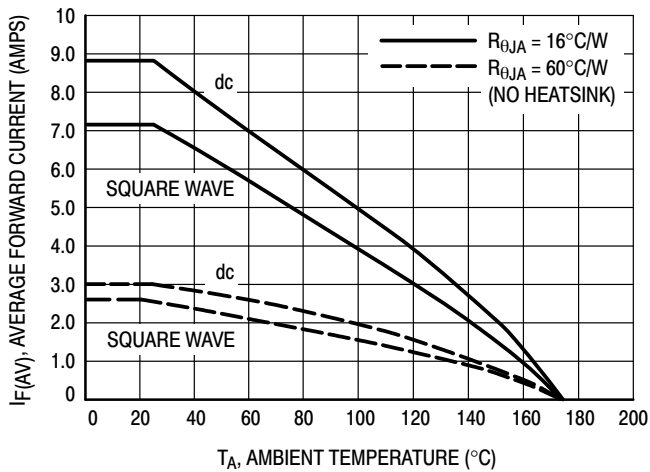


Figure 14. Current Derating, Ambient, Per Leg

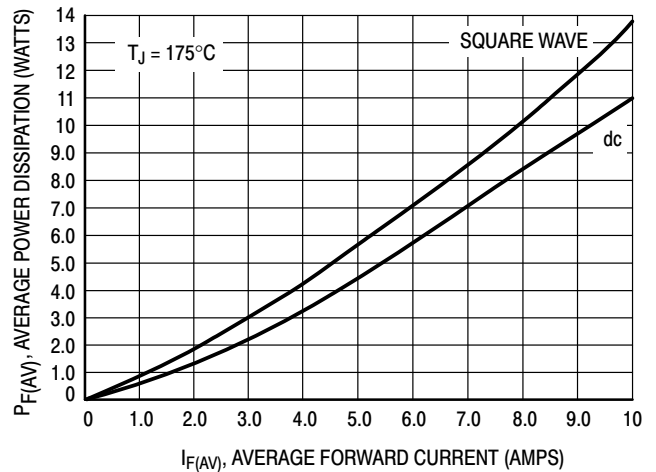


Figure 15. Power Dissipation, Per Leg

# MUR1610CTG, MUR1615CTG, MUR1620CTG, MUR1640CTG, MUR1660CTG

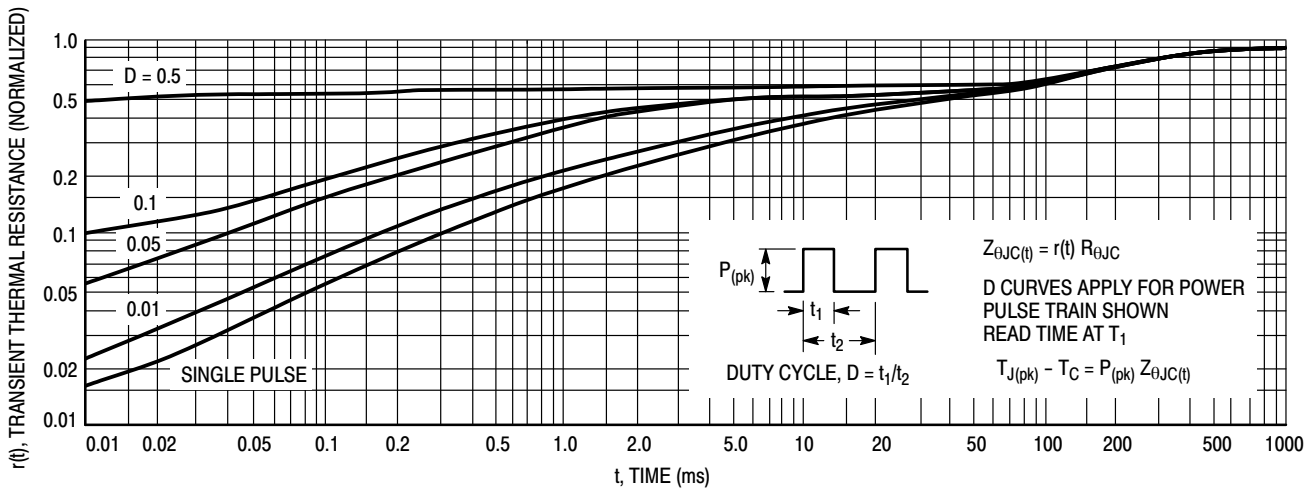


Figure 16. Thermal Response

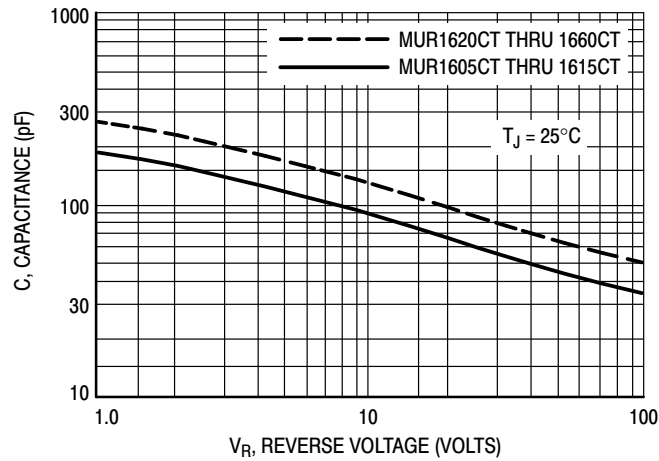


Figure 17. Typical Capacitance, Per Leg

## ORDERING INFORMATION

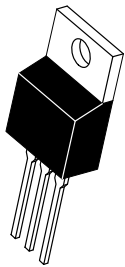
Device	Package	Shipping†
MUR1610CTG	TO-220 (Pb-Free)	50 Units / Rail
MUR1615CTG	TO-220 (Pb-Free)	
MUR1620CTG	TO-220 (Pb-Free)	
MUR1640CTG	TO-220 (Pb-Free)	
MUR1660CTG	TO-220 (Pb-Free)	

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# MECHANICAL CASE OUTLINE

## PACKAGE DIMENSIONS

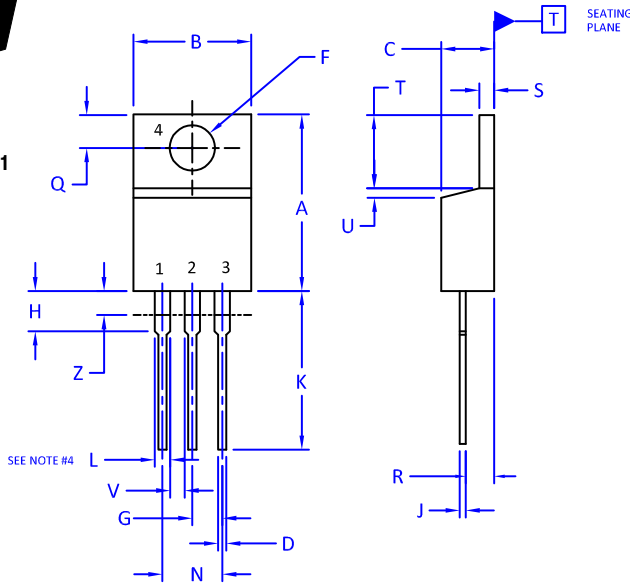
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SCALE 1:1

### TO-220 CASE 221A-09 ISSUE AJ

DATE 05 NOV 2019



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 2009.
2. CONTROLLING DIMENSION: INCHES
3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.
4. MAX WIDTH FOR F102 DEVICE = 1.35MM

DIM	INCHES		MILLIMETERS	
	MIN.	MAX.	MIN.	MAX.
A	0.570	0.620	14.48	15.75
B	0.380	0.415	9.66	10.53
C	0.160	0.190	4.07	4.83
D	0.025	0.038	0.64	0.96
F	0.142	0.161	3.60	4.09
G	0.095	0.105	2.42	2.66
H	0.110	0.161	2.80	4.10
J	0.014	0.024	0.36	0.61
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.41
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045	---	1.15	---
Z	---	0.080	---	2.04

STYLE 1:

- PIN 1. BASE
- 2. COLLECTOR
- 3. EMITTER
- 4. COLLECTOR

STYLE 2:

- PIN 1. BASE
- 2. EMITTER
- 3. COLLECTOR
- 4. EMITTER

STYLE 3:

- PIN 1. CATHODE
- 2. ANODE
- 3. GATE
- 4. ANODE

STYLE 4:

- PIN 1. MAIN TERMINAL 1
- 2. MAIN TERMINAL 2
- 3. GATE
- 4. MAIN TERMINAL 2

STYLE 5:

- PIN 1. GATE
- 2. DRAIN
- 3. SOURCE
- 4. DRAIN

STYLE 6:

- PIN 1. ANODE
- 2. CATHODE
- 3. ANODE
- 4. CATHODE

STYLE 7:

- PIN 1. CATHODE
- 2. ANODE
- 3. CATHODE
- 4. ANODE

STYLE 8:

- PIN 1. CATHODE
- 2. ANODE
- 3. EXTERNAL TRIP/DELAY
- 4. ANODE

STYLE 9:

- PIN 1. GATE
- 2. COLLECTOR
- 3. EMITTER
- 4. COLLECTOR

STYLE 10:

- PIN 1. GATE
- 2. SOURCE
- 3. DRAIN
- 4. SOURCE

STYLE 11:

- PIN 1. DRAIN
- 2. SOURCE
- 3. GATE
- 4. SOURCE

STYLE 12:

- PIN 1. MAIN TERMINAL 1
- 2. MAIN TERMINAL 2
- 3. GATE
- 4. NOT CONNECTED

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